

## NPN SILICON TRANSISTOR

Qualified per MIL-PRF-19500/366

### Devices

2N3498	2N3499	2N3500	2N3501
2N3498L	2N3499L	2N3500L	2N3501L

### Qualified Level

JAN  
JANTX  
JANTXV  
JANS

### MAXIMUM RATINGS

Ratings	Symbol	2N3498* 2N3499*	2N3500* 2N3501*	Unit
Collector-Emitter Voltage	$V_{CE0}$	100	150	Vdc
Collector-Base Voltage	$V_{CBO}$	100	150	Vdc
Emitter-Base Voltage	$V_{EBO}$	6.0	6.0	Vdc
Collector Current	$I_C$	500	300	mAdc
Total Power Dissipation	$P_T$	1.0 5.0		W
		@ $T_A = 25^{\circ}C$ <sup>(1)</sup> @ $T_C = 25^{\circ}C$ <sup>(2)</sup>		
Operating & Storage Junction Temp. Range	$T_J, T_{stg}$	-55 to +200		$^{\circ}C$

### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max.	Unit
Thermal Resistance: Junction-to-Case	$R_{\theta JC}$	35	$^{\circ}C/W$
Junction-to-Ambient	$R_{\theta JA}$	175	

\*Electrical characteristics for "L" suffix devices are identical to the "non L" corresponding devices

1) Derate linearly 5.71 W/ $^{\circ}C$  for  $T_A > 25^{\circ}C$

2) Derate linearly 28.6 W/ $^{\circ}C$  for  $T_C > 25^{\circ}C$



TO-5\*  
2N3498L, 2N3499L  
2N3500L, 2N3501L



TO-39\* (TO-205AD)  
2N3498, 2N3499  
2N3500, 2N3501

\*See appendix A for package outline

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristics	Symbol	Min.	Max.	Unit
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#### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage $I_C = 10$ mAdc	2N3498, 2N3499 2N3500, 2N3501	$V_{(BR)CE0}$	100 150	Vdc
Collector-Base Cutoff Current $V_{CB} = 50$ Vdc $V_{CB} = 75$ Vdc $V_{CB} = 100$ Vdc $V_{CB} = 150$ Vdc	2N3498, 2N3499 2N3500, 2N3501 2N3498, 2N3499 2N3500, 2N3501	$I_{CBO}$	50 50 10 10	$\eta$ Adc $\eta$ Adc $\mu$ Adc $\mu$ Adc
Emitter-Base Cutoff Current $V_{EB} = 4.0$ Vdc $V_{EB} = 6.0$ Vdc		$I_{EBO}$	25 10	$\eta$ Adc $\mu$ Adc

**ELECTRICAL CHARACTERISTICS (con't)**

Characteristics	Symbol	Min.	Max.	Unit
<b>ON CHARACTERISTICS</b> <sup>(3)</sup>				
Forward-Current Transfer Ratio $I_C = 0.1 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ 2N3498, 2N3500 2N3499, 2N3501 $I_C = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ 2N3498, 2N3500 2N3499, 2N3501 $I_C = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ 2N3498, 2N3500 2N3499, 2N3501 $I_C = 150 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ 2N3498, 2N3500 2N3499, 2N3501 $I_C = 300 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ 2N3500 2N3501 $I_C = 500 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$ 2N3498 2N3499	$h_{FE}$	20 35 25 50 35 75 40 100 15 20 15 20	120 300	
Collector-Emitter Saturation Voltage $I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$ $I_C = 300 \text{ mAdc}, I_B = 30 \text{ mAdc}$ $I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc}$ All Types 2N3498, 2N349 2N3500, 2N3501	$V_{CE(sat)}$		0.2 0.6 0.4	Vdc
Base-Emitter Saturation Voltage $I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$ $I_C = 300 \text{ mAdc}, I_B = 30 \text{ mAdc}$ $I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc}$ All Types 2N3498, 2N3499 2N3500, 2N3501	$V_{BE(sat)}$		0.8 1.4 1.2	Vdc
<b>DYNAMIC CHARACTERISTICS</b>				
Forward Current Transfer Ratio, Magnitude $I_C = 20 \text{ mAdc}, V_{CE} = 20 \text{ Vdc}, f = 100 \text{ MHz}$	$ h_{fe} $	1.5	8.0	
Output Capacitance $V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$ 2N3498, 2N3499 2N3500, 2N3501	$C_{obo}$		10 8.0	pF
Input Capacitance $V_{EB} = 0.5 \text{ Vdc}, I_C = 0, 100 \text{ kHz} \leq f \leq 1.0 \text{ MHz}$	$C_{ibo}$		80	pF
<b>SWITCHING CHARACTERISTICS</b>				
Turn-On Time $V_{EB} = 5 \text{ Vdc}; I_C = 150 \text{ mAdc}; I_{B1} = 15 \text{ mAdc}$	$t_{on}$		115	$\eta s$
Turn-Off Time $I_C = 150 \text{ mAdc}; I_{B1} = I_{B2} = -15 \text{ mAdc}$	$t_{off}$		1150	$\eta s$
<b>SAFE OPERATING AREA</b>				
<b>DC Tests</b> $T_C = +25^\circ C, t_r \geq 10 \eta s; 1 \text{ Cycle}, t = 1.0 \text{ s}$				
<b>Test 1</b> $V_{CE} = 10 \text{ Vdc}, I_C = 500 \text{ mAdc}$ 2N3498, 2N3499 $V_{CE} = 16.67 \text{ Vdc}, I_C = 300 \text{ mAdc}$ 2N3500, 2N3501				
<b>Test 2</b> $V_{CE} = 50 \text{ Vdc}, I_C = 100 \text{ mAdc}$ All Types				
<b>Test 3</b> $V_{CE} = 80 \text{ Vdc}, I_C = 40 \text{ mAdc}$ All Types				
<b>Clamped Switching</b> $T_A = +25^\circ C$				
<b>Test 1</b> $I_B = 85 \text{ mAdc}, I_C = 500 \text{ mAdc}$ 2N3498, 2N3499 $I_B = 50 \text{ mAdc}, I_C = 300 \text{ mAdc}$ 2N3500, 2N3501				

(3) Pulse Test: Pulse Width = 300 $\mu s$ , Duty Cycle  $\leq 2.0\%$ .